



**SDM160S1F** 

**1A SCHOTTKY** 

#### **Product Summary**

V <sub>RRM</sub> (V)	I <sub>O</sub> (A)	V <sub>F</sub> Max (V) @ +25°C	I <sub>R</sub> Max (mA) @ +25°C
60	1	0.53	0.06

### **Features and Benefits**

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- Interlocking Clip Design for High Surge Current Capacity
- Qualified to AEC-Q101 Standards
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

## **Description and Applications**

The SDM160S1F is a single rectifier packaged in SOD123F. Offering low V<sub>F</sub>, low power loss and high efficiency, this device is ideal for use in general rectification applications as a:

- **Boost Diode**
- **Blocking Diode**

#### **Mechanical Data**

- Case: SOD123F
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Polarity: Cathode Band
- Weight: 0.015 grams (Approximate)

#### SOD123F



Top View

### Ordering Information (Note 4)

Part Number	Case	Packaging
SDM160S1F-7	SOD123F	3,000/Tape & Reel

Notes:

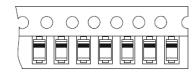
- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



D6 = Product Type Marking Code YM = Date Code Marking Y = Year (ex.: D = 2016)

M = Month (ex.: 9 = September) Bar Denotes Cathode Pin



Bar Denotes Cathode Pin

#### Date Code Key

Yea	r	2013	2014	2015	2016	2017	2018	2019	2020
Cod	е	Α	В	С	D	Е	F	G	Н

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# 

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>RM</sub>	60	٧
Average Rectified Output Current	lo	1	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	50	А

### **Thermal Characteristics**

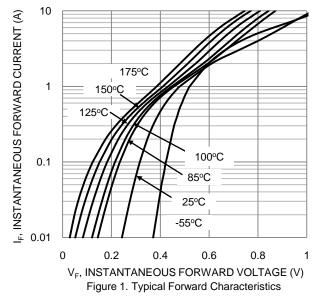
Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Case (Note 5) Typical Thermal Resistance Junction to Ambient (Note 5)	R <sub>0JC</sub> R <sub>0JA</sub>	66 100	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C

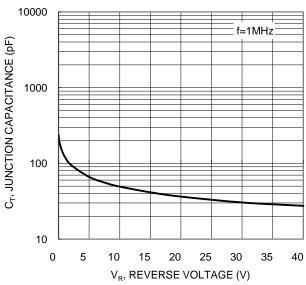
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

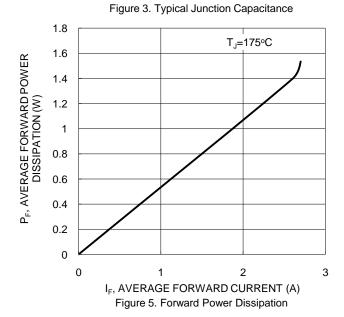
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 6)	V <sub>(BR)R</sub>	60		_	V	$I_R = 1.0 \text{mA}$
		_	0.32	0.37		$I_F = 0.1A, T_J = +25^{\circ}C$
Forward Voltage Drop	VF	_	0.43	0.49	V	$I_F = 0.7A, T_J = +25^{\circ}C$
		_	0.46	0.53		$I_F = 1A$ , $T_J = +25$ °C
			0.002	_		$V_R = 10V, T_J = +25^{\circ}C$
Leakage Current (Note 6)	I <sub>R</sub>	_	0.010	0.060	mA	$V_R = 60V, T_J = +25^{\circ}C$
Leakage Current (Note 6)			0.40		IIIA	$V_R = 60V, T_J = +85^{\circ}C$
		_	3.7	_		$V_R = 60V, T_J = +125$ °C
Total Capacitance	C <sub>T</sub>	_	48	_	pF	$V_R = 10V$ , $f = 1MHz$

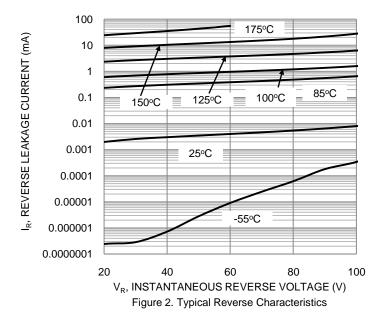
5. Device mounted on FR-4 substrate, 1.0"\*1.0", 2oz, single-sided, PC boards with 0.2"\*0.25" copper pad. 6. Short duration pulse test used to minimize self-heating effect. Notes:

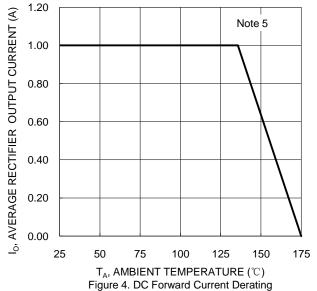










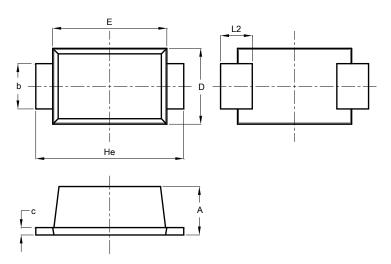




## **Package Outline Dimensions**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.

#### SOD123F

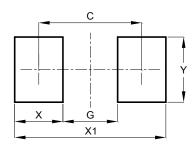


SOD123F							
Dim	Min	Max	Тур				
A	0.81	1.15	-				
Ь	0.80	1.35	-				
U	0.05	0.30	-				
D	1.70	1.90	1.80				
Е	2.60	2.80	2.70				
He	3.30	3.70	3.50				
L2	0.35	0.85	-				
AII [	Dimen	sions	in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.

#### SOD123F



Dimensions	Value (in mm)
С	2.86
G	1.52
Х	1.34
X1	4.20
Υ	1.80



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